

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,867,064 B2
DATED : March 15, 2005
INVENTOR(S) : Kristy A. Campbell et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page,

Item [56], **References Cited**, U.S. PATENT DOCUMENTS, "5,335,519 A 8/1994 Bernie" should read -- 5,335,219 8/1994 Ovshinsky et al. --

OTHER PUBLICATIONS, "El Bouchairi, B.; Bernede, J.C.; reference, "El Bouchairi, B.; Bernede, J.C.; Burgaud, P., Properties of $\text{Ag}_{2-x}\text{Se}_{1+x}/\text{n-Si}$ diodes, Thin Solid Films 110 (1983) 107-113." should read -- El Bouchairi, B.; Bernede, J.C.; Burgaud, P., Properties of $\text{Ag}_{2-x}\text{Se}_{1+x}/\text{n-Si}$ diodes, Thin Solid Films 110 (1983) 107-113. --

"Feng, X.; Bresser," reference "Feng, X.; Bresser, W.J.; Boolchand, P., Directed evidence for stiffness threshold in Chalcogenide glasses, Phys. Rev. Lett. 78 (1997) 4422-4425." should read -- Feng, X.; Bresser, W.J.; Boolchand, P., Direct evidence for stiffness threshold in chalcogenide glasses, Phys. Rev. Lett. 78 (1997) 4422-4425. --

"Hosokawa, S., reference, "Hosokawa, S., Atomic and electronic structures of glassy $\text{Ge}_{1-x}\text{Se}_x$ around the stiffness threshold composition, J. Optoelectronics and Advanced Materials 3 (2001) 199-214." should read -- Hosokawa, S., Atomic and electronic structures of glassy $\text{Ge}_{1-x}\text{Se}_x$ around the stiffness threshold composition, J. Optoelectronics and Advanced Materials 3 (2001) 199-214. --

"Mitkova, M.; Wang, Y Boolchand, P.," reference Dual chemical role of Ag as an additive in chalcogenide glasses Phys. Rev. Lett. 83 (1999) 3848-3851." should read -- Mitkova, M.; Wang, Y.; Boolchand, P., Dual chemical role of Ag as an additive in chalcogenide glasses, Phys. Rev. Lett. 83 (1999) 3848- 3851. --

"Yoji Kawamoto et al." reference, "Ionic Conduction in $\text{As}_2\text{S}_3\text{-Ag}_2\text{S, GeS}_2\text{-GeS-Ag}_2\text{S}$ and $\text{P}_2\text{S}_5\text{-Ag}_2\text{S}$ Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404." should read -- Yoji Kawamoto et al., "Ionic Conduction in $\text{As}_2\text{S}_3\text{-Ag}_2\text{S, GeS}_2\text{-GeS-Ag}_2\text{S}$ and $\text{P}_2\text{S}_5\text{-Ag}_2\text{S}$ Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404. --.

This certificate supersedes Certificate of Correction issued June 28, 2005.

Signed and Sealed this

Eleventh Day of October, 2005



JON W. DUDAS
Director of the United States Patent and Trademark Office